TOSHIBA Field Effect Transistor Silicon N-Channel Dual Gate MOS Type

3SK291

TV Tuner, UHF RF Amplifier Applications

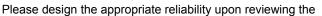
Unit: mm

- Superior cross modulation performance
- Low reverse transfer capacitance: $C_{rss} = 0.016 \text{ pF (typ.)}$
- Low noise figure: NF = 1.5dB (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	12.5	V
Gate 1-source voltage	V _{G1S}	±8	V
Gate 2-source voltage	V _{G2S}	±8	V
Drain current	I _D	30	mA
Drain power dissipation	P _D	150	mW
Channel temperature	T _{ch}	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



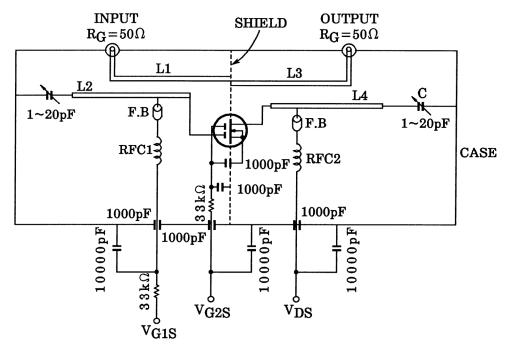
Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

1. GATE 1 2. GATE 2 3. DRAIN 4. SOURCE JEDEC JEITA TOSHIBA 2.9-0.3 0.85 1.0-0.15 5° 8° 0.85 1.00-1:1 2.000-1:1

Weight: 0.013 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate 1 leakage current	I _{G1SS}	$V_{DS} = 0$, $V_{G1S} = \pm 6$ V, $V_{G2S} = 0$	_	_	±50	nA
Gate 2 leakage current	I _{G2SS}	$V_{DS} = 0, V_{G1S} = 0, V_{G2S} = \pm 6 \text{ V}$	_	_	±50	nA
Drain-source voltage	V (BR) DSX	$\begin{aligned} V_{G1S} &= -0.5 \; V, V_{G2S} = -0.5 \; V, \\ I_D &= 100 \; \mu A \end{aligned}$	12.5	_	_	٧
Drain current	I _{DSS}	$V_{DS} = 6 \text{ V}, V_{G1S} = 0, V_{G2S} = 4.5 \text{ V}$	_	_	0.1	mA
Gate 1-source cut-off voltage	V _{G1S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G2S} = 4.5 \text{ V}, I_D = 100 \mu A$	0.3	0.8	1.3	V
Gate 2-source cut-off voltage	V _{G2S} (OFF)	$V_{DS} = 6 \text{ V}, V_{G1S} = 4.0 \text{ V}, I_D = 100 \mu A$	0.5	1.0	1.5	V
Forward transfer admittance	Y _{fs}	V_{DS} = 6 V, V_{G2S} = 4.5 V, I_D = 10 mA, f = 1 kHz	22	26	_	mS
Input capacitance	C _{iss}	V _{DS} = 6 V, V _{G2S} = 4.5 V, I _D = 10 mA,	_	2.0	2.6	pF
Reverse transfer capacitance	C _{rss}	f = 1 MHz	_	16	40	fF
Power gain	G _{ps}	V _{DS} = 6 V, V _{G2S} = 4.5 V, I _D = 10 mA,	20	22.5	_	dB
Noise figure	NF	f = 800 MHz (Figure 1)	_	1.5	2.5	dB



L1~L4: φ0.8 mm silver plated copper wire

C: Air trimmer TTA25A200A (MURATA Manufacturing, Co., Ltd.)

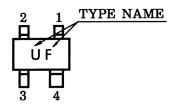
RFC 1: $\phi 0.35$ mm copper wire 3 mm ID, 7 T

RFC 2: $\phi 0.35$ mm copper wire 3 mm ID, 10 T

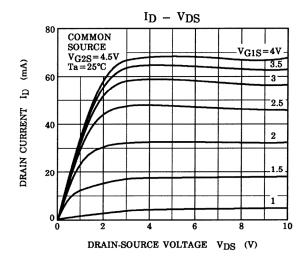
Figure 1 800 MHz Gps, NF Test Circuit

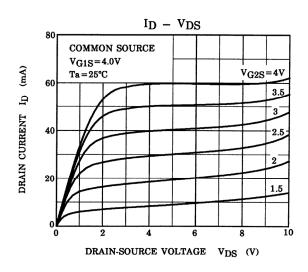
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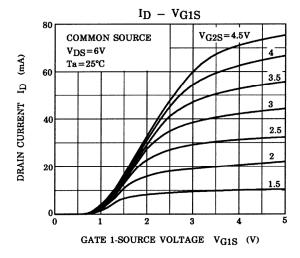
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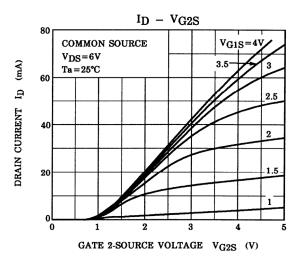


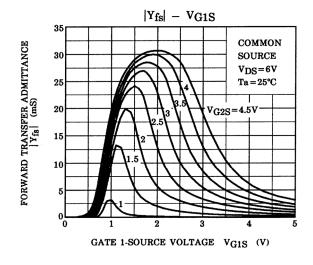
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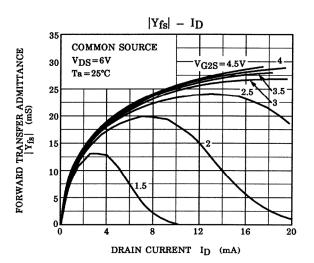






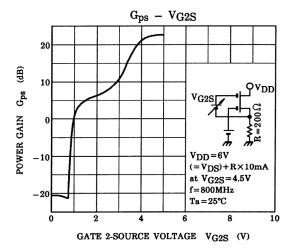


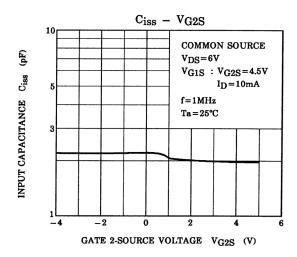


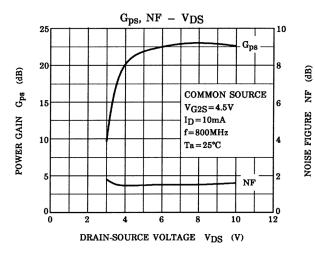


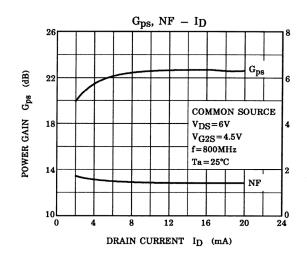
(dB)

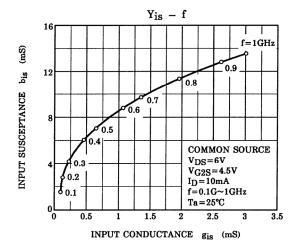
NOISE FIGURE NF

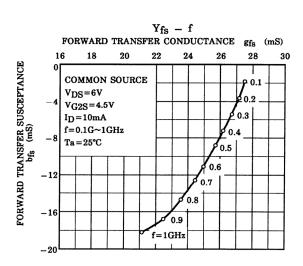


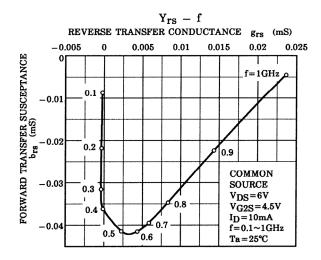


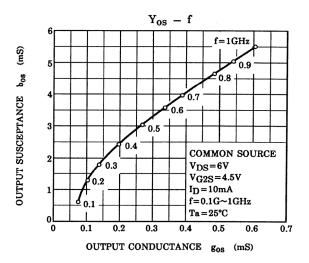


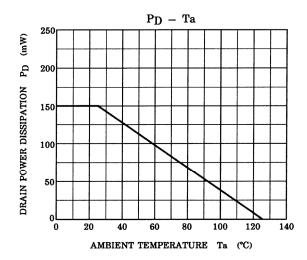












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